

Series Optically Coupled Isolators BASEEFA & ATEX CERTIFIED

OPI 1264

The OPI1264A/B/C/D are a family of optically coupled isolators, each consisting of a infrared light emitting diode, coupled to an NPN silicon phototransistor sealed in an injection moulded plastic housing. This series is designed for applications requiring high voltage isolation between input and output.

All electrical parameters are 100% tested by manufacturing. Specifications are guaranteed to a 0.65% AQL

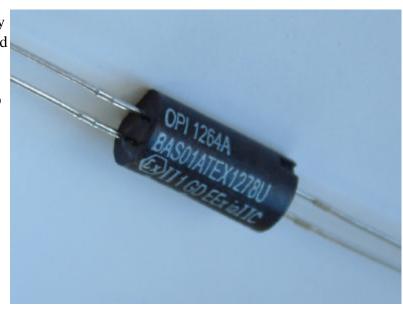
- 10KV electrical rating
- High current transfer ratio-100% min@
 1m
- Designed and manufactured to EN50020 1995 and EN50014 1998

BASEEFA CERTIFIED

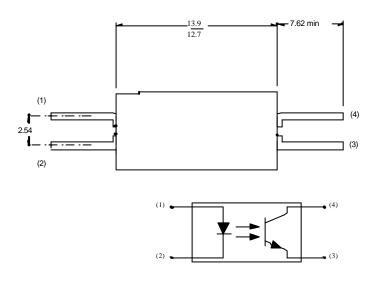
BAS No. Ex89C2096UEExiaIIC

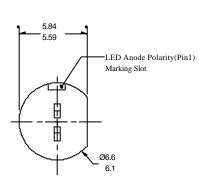
ATEX CERTIFIED

BAS01ATEX1278U



MECHANICAL DATA





CONDITION OF USE APPLY EN50020 1994 CLAUSES 6..4.9 AND 8.8

BEDFORD OPTO TECHNOLOGY LTD LINDSAYLANDS, BIGGAR, LANARKSHIRE ML12 6NR

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INPUT DIODE FORWARD DC CURRENT REVERSE DC VOLTAGE	50mA (3) 2V
OUTPUT PHOTOTRANSISTOR COLLECTOR-EMITTER VOLTAGE EMITTER-COLLECTOR VOLTAGE	30 V 5 V
OPERATING TEMP	-40°C TO +85°C
STORAGE TEMP	-40°C TO +85°C
INPUT-TO-OUTPUT ISOLATION VOLTAGE	+10KV DC (1)
LEAD SOLDERING TEMP (2) 1.6mm from case for 5sec with	240°C

NOTES

- 1 Measured with input diode leads shorted together and output leads shorted together.
- 2 RMA Flux is recommended. Duration can be extended to 10 sec. max. when flow soldering.
- 3 Derate linearly 0.73 mA/°C above 25°C
- 4 Derate linearly 1.67 mW/°C above 25°C
- 5 Derate linearly 1.67 mW/°C above 25°C

Whilst the devices are capable of operating continually at the noted elevated

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OPTO ELECTRONIC DATA ($TA = 25^{\circ}C$)

PARAMETER	SYMBOL	MIN	ТҮР	MAX	UNITS	TEST CONDIS- TIONS
INPUT DIODE						
Forward Voltage	VF			1.5	V	If = 20mA
Reverse Current	Ir			100	ì A	Vr = 2V
OUTPUT PHOTOTRANSISTOR						
Collector-Emitter Breakdown Volt-	V(BR)CEO	30			V	Ic = 1 mA If = 0
Emitter-Collector Breakdown Volt-	V(BR)ECO	5			V	Ie = 100ì A
Collector-Emitter Dark Current	Iceo			100	nA	Vce = 10V
COUPLED CHARACTERISTICS						
DC Current transfer ratio	Ic/If					
OPI 1264A		25			%	If=10mA, Vce=5V
OPI 1264B		50			%	If=10mA, Vce=5V
OPI 1264C		100			%	If=10mA, Vce=5V
OPI 1264D		100			%	If=1mA, Vce=5V
Isolation Voltage	Viso	10			KV	See Note
Collector-emitter saturation voltage	VCE(SAT)			0.4	V	If=10mA,
Turn-on time	t on		5		ì S	Ic=10mA, Vcc=10V,
Turn-off time	t off		5		ìS	Ic=10mA, Vcc=10V,

NOTE:

Measured with input diode leads shorted together and output leads shorted together. (Sample testing only).

OPTO ELECTRONIC SOLUTIONS

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ESSENTIAL HEALTH AND SAFETY INFOR-MATION IN ACCORDANCE WITH ATEX DI-RECTIVE 94/9/EC

INFORMATION CONTAINED IN THIS DATASHEET IS DEEMED TO CONFORM TO THE ABOVE DIRECTIVE AND IS SUPPLIED IN RELATION TO THE FOLLOWING SHIPMENT:-

CUSTOMER
ORDER NUMBER
INVOICE NUMBER
TYPE NUMBER
QUANTITY
BATCH NUMBER
DATE CODE
DATE OF SHIPMENT